

Features

- Ultra low capacitance: 0.35pF typical
- Ultra low leakage: nA level
- Low operating voltage: : 5V
- Low clamping voltage
- Complies with following standards:
 - – IEC 61000-4-2 (ESD) immunity test
 - Air discharge: ±25kV
 - Contact discharge: ±22kV
 - – IEC61000-4-5 (Lightning)4A (8/20µs)
- RoHS Compliant
- Lead Finish: NiPdAu

Mechanical Characteristics

- Package: SOT-23
- Lead Finish: Matte Tin
- Case Material: “Green” Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below

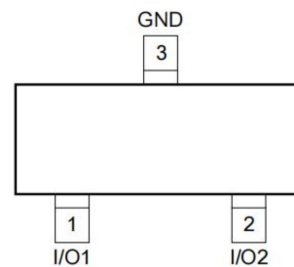
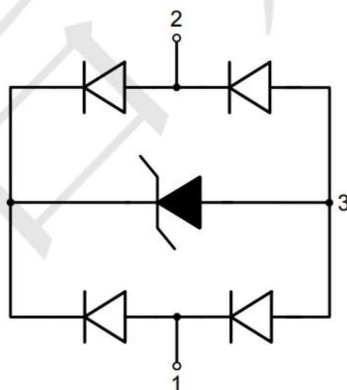
Applications

- Laptop Computers
- Cellular Phones
- Digital Cameras
- Personal Digital Assistants (PDAs)

Ordering Information

Part Number	Qty per Reel	Reel Size
ESD5302F	3000	7"

Dimensions and Pin Configuration



Marking:WAQ Or W02L

Absolute Maximum Ratings (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	75	W
Peak Pulse Current (8/20μs)	Ipp	4	A
ESD per IEC 61000-4-2 (Air)	VESD	±25	kV
ESD per IEC 61000-4-2 (Contact)		±22	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6.5		9	V	IT = 1mA
Reverse Leakage Current	IR			0.08	uA	VRWM = 5V
Clamping Voltage	VC			9	V	Ipp=1A(8x 20us pulse)
Clamping Voltage	VC			14	V	Ipp=4A(8x 20us pulse)
Junction Capacitance	CJ		0.5	0.6	pF	VR = 0V, f = 1MHz (IO to GND)
Junction Capacitance	CJ		0.35		pF	VR = 0V, f = 1MHz (IO to IO)

Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)

Fig1. 8/20 μs Pulse Waveform

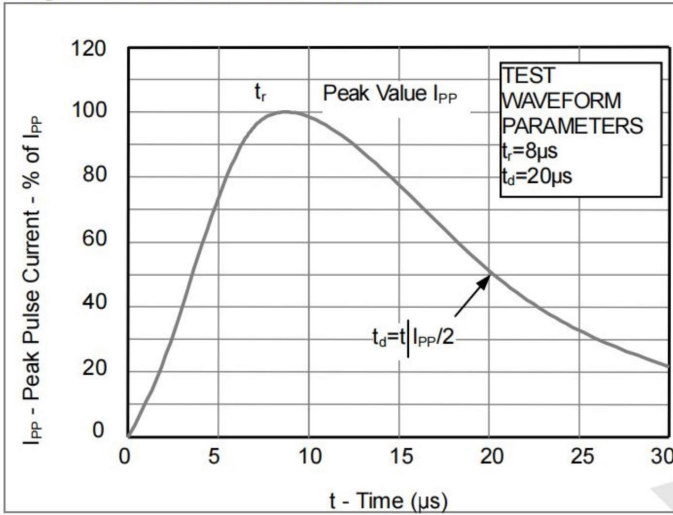


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

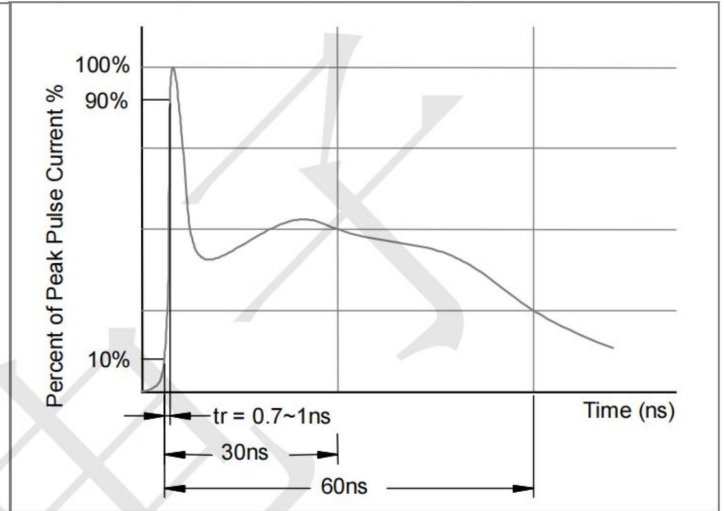
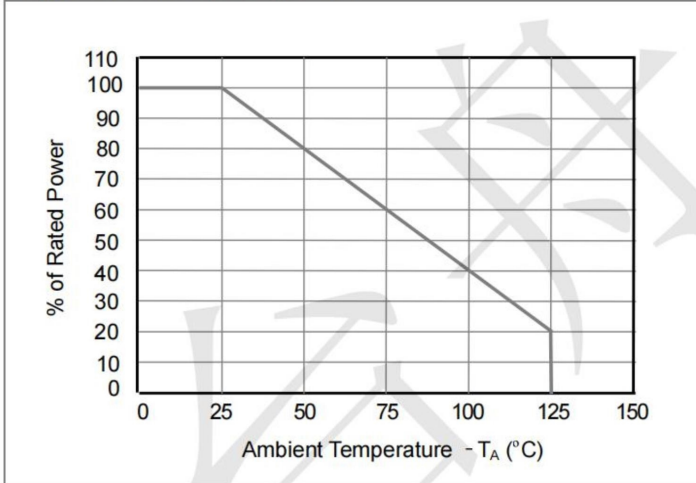
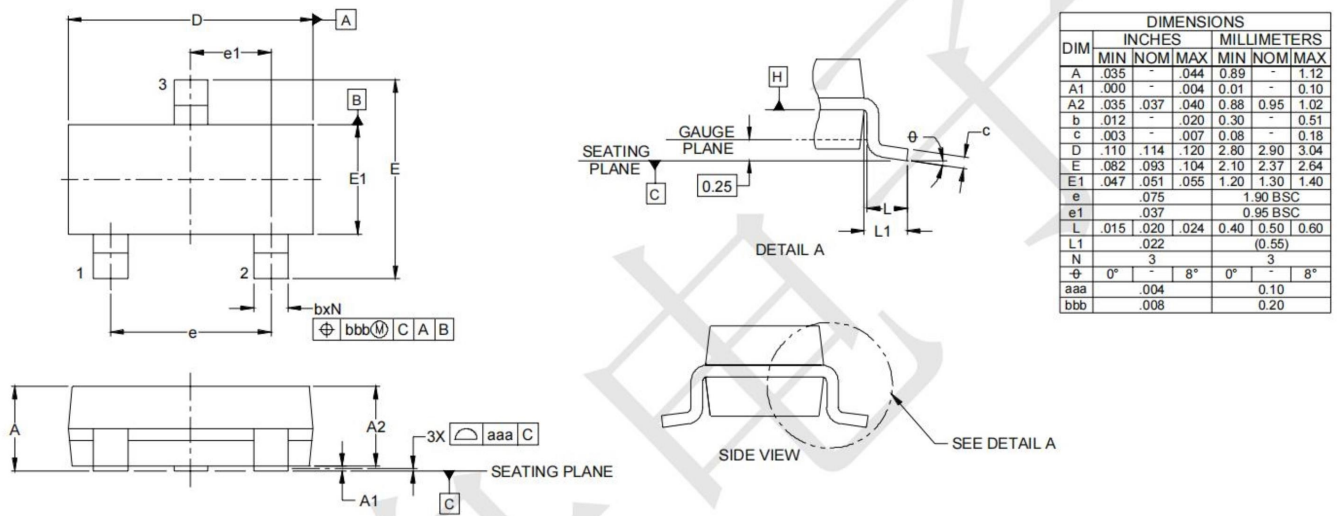


Fig3. Power Derating Curve



Outline Drawing - SOT23



Land Pattern - SOT23

